AlGaInP Laser Diodes

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Description

The HL6312/13G are $0.63~\mu m$ band AlGaInP laser diodes with a multi-quantum well (MQW) structure. Wavelength is equal to He-Ne Gas laser. They are suitable as light sources in bar code readers, laser levelers and various other types of optical equipment. Hermetic sealing of the package achieves high reliability.

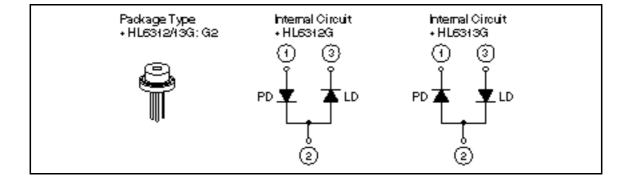
Features

• Visible light output: p = 635 nm Typ (nearly equal to He-Ne Gas Laser)

Optical output power: 5 mW CWLow Operating voltage: 2.7 V Max

• Single longitudinal mode

· Built-in photodiode for monitoring laser output





Absolute Maximum Ratings $(T_C = 25^{\circ}C)$

Item	Symbol	Rated Value	Unit	
Optical output power	Po	5	mW	
Pulse optical output power	P _{O (pulse)}	6* ¹	mW	
LD reverse voltage	V _{R (LD)}	2	V	
PD reverse voltage	$V_{R (PD)}$	30	V	
Operating temperature	Topr	-10 to +50	°C	
Storage temperature	Tstg	-40 to +85	°C	

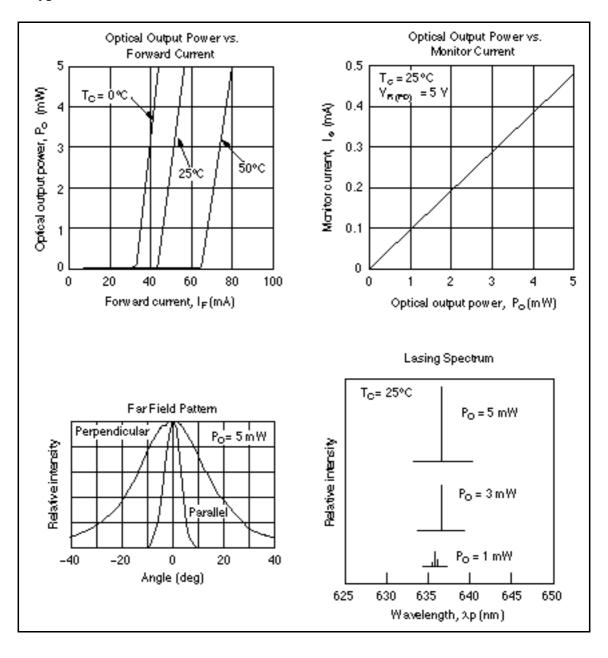
Note: 1. Pulse condition: Pulse width 1 µs, duty 50%

Optical and Electrical Characteristics ($T_{\scriptscriptstyle C}=25^{\circ}C)$

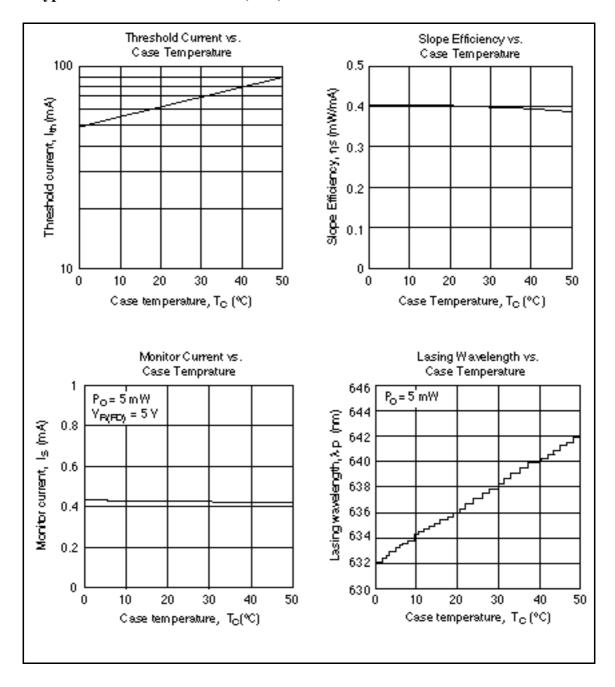
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Optical output power	Po	5	_	_	mW	Kink free
Threshold current	lth	20	45	70	mA	
Operating current	lop	_	55	85	mA	$P_o = 5 \text{ mW}$
Operating voltage	Vop	_	_	2.7	V	$P_0 = 5 \text{ mW}$
Lasing wavelength	р	625	635	640	nm	$P_0 = 5 \text{ mW}$
Beam divergence (parallel)	//	5	8	11	deg.	$P_o = 5 \text{ mW}$
Beam divergence (perpendicular)		25	31	37	deg.	$P_{o} = 5 \text{ mW}$
Monitor current	Is	0.2	0.4	0.8	mA	$P_0 = 5 \text{ mW}, V_R = 5 \text{ V}$

100 HITACHI

Typical Characteristic Curves

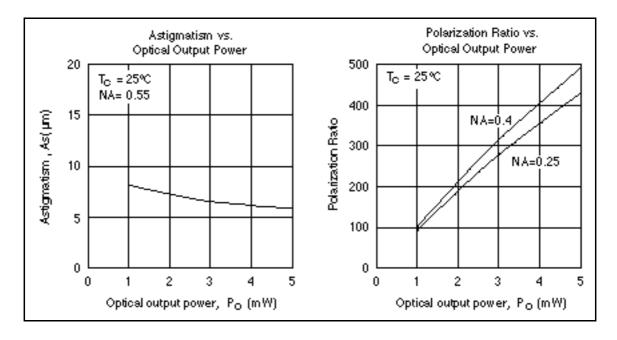


Typical Characteristic Curves (cont)



102 HITACHI

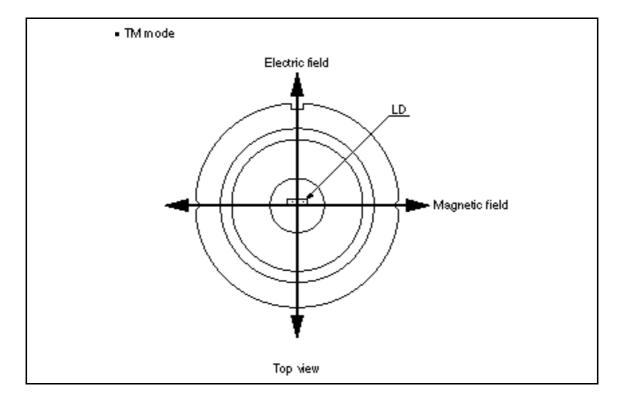
Typical Characteristic Curves (cont)



104

Polarization direction

The polarization direction is TM mode. The polarization direction of 0.63 μm LD's is different from that of 0.83/0.78/0.67 μm LD's. The polarization direction of 0.63 μm LD's is illustrated in the figure below.



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